## NPN Silicon Epitaxial Planar Transistor

As complementary types the PNP transistors 2N3905 and 2N3906 are recommended.

On special request, these transistors can be manufactured in different pin configurations.


1. Emitter 2. Base 3. Collecto TO-92 Plastic Package

## Applications

- For switching and amplifier

Absolute Maximum Ratings $\left(\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}\right)$

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector Base Voltage | $\mathrm{V}_{\text {CBO }}$ | 60 | V |
| Collector Emitter Voltage | $\mathrm{V}_{\text {CEO }}$ | 40 | V |
| Emitter Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 6 | V |
| Collector Current | $\mathrm{I}_{\mathrm{C}}$ | 200 | mA |
| Total Power Dissipation | $\mathrm{P}_{\text {tot }}$ | 625 | mW |
| Operating Junction and Storage Temperature Range | $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Thermal Characteristics

| Parameter | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| Thermal Resistance from Junction to Ambient | $R_{\text {өJA }}$ | 200 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Characteristics at $\mathrm{T}_{\mathrm{a}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$

| Parameter |  | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { DC Current Gain } \\ & \text { at } \mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0.1 \mathrm{~mA} \\ & \text { at } \mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA} \\ & \text { at } \mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \text { at } \mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA} \\ & \text { at } \mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & \text { 2N3903 } \\ & \text { 2N3904 } \\ & \text { 2N3903 } \\ & \text { 2N3904 } \\ & \text { 2N3903 } \\ & \text { 2N3904 } \\ & \text { 2N3903 } \\ & \text { 2N3904 } \\ & \text { 2N3903 } \\ & \text { 2N3904 } \end{aligned}$ | $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ <br> $h_{\text {FE }}$ | $\begin{gathered} 20 \\ 40 \\ 35 \\ 70 \\ 50 \\ 100 \\ 30 \\ 60 \\ 15 \\ 30 \\ \hline \end{gathered}$ | $\begin{aligned} & 150 \\ & 300 \end{aligned}$ |  |
| Collector Base Cutoff Current at $\mathrm{V}_{\mathrm{CB}}=30 \mathrm{~V}$ |  | $\mathrm{I}_{\text {CBO }}$ | - | 50 | nA |
| Emitter Base Cutoff Current at $V_{E B}=6 \mathrm{~V}$ |  | $\mathrm{I}_{\text {Ebo }}$ | - | 50 | nA |
| Collector Base Breakdown Voltage at $I_{C}=10 \mu \mathrm{~A}$ |  | $V_{\text {(BR)cbo }}$ | 60 | - | V |
| Collector Emitter Breakdown Voltage $\text { at } \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |  | $V_{\text {(BR)CEO }}$ | 40 | - | V |
| Emitter Base Breakdown Voltage at $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}$ |  | $V_{\text {(BR)Ebo }}$ | 6 | - | V |
| Collector Emitter Saturation Voltage at $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ at $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=5 \mathrm{~mA}$ |  | $V_{\text {CE(sat) }}$ | - | $\begin{aligned} & 0.2 \\ & 0.3 \end{aligned}$ | V |
| Base Emitter Saturation Voltage at $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ at $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=5 \mathrm{~mA}$ |  | $V_{\text {bE(sat) }}$ | - | $\begin{aligned} & 0.85 \\ & 0.95 \end{aligned}$ | V |
| Gain Bandwidth Product at $V_{C E}=20 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}$ | $\begin{aligned} & \text { 2N3903 } \\ & \text { 2N3904 } \end{aligned}$ | $\mathrm{f}_{\mathrm{T}}$ | $\begin{aligned} & 250 \\ & 300 \end{aligned}$ | - | MHz |
| Collector Base Capacitance at $\mathrm{V}_{\mathrm{CB}}=5 \mathrm{~V}, \mathrm{f}=100 \mathrm{KHz}$ |  | $\mathrm{C}_{\text {ob }}$ | - | 4 | pF |
| Delay Time $\text { at } \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BE}}=0.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=1 \mathrm{~mA}$ |  | $t_{d}$ | - | 35 | ns |
| Rise Time at $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BE}}=0.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=1 \mathrm{~mA}$ |  | $\mathrm{t}_{\mathrm{r}}$ | - | 35 | ns |
| Storage Time at $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=-\mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~mA}$ |  | $\mathrm{t}_{\text {s }}$ | - | 200 | ns |
| Fall Time <br> at $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=-\mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~mA}$ |  | $\mathrm{t}_{\mathrm{f}}$ | - | 50 | ns |

## Electrical Characteristics Curves

Fig. 1 Power Derating Curve


Fig. 3 Collector Curren vs. $V_{B E}$


Fig. 2 Output Characteristics Curve


Fig. $4 h_{\text {fe }}$ vs. Collector Current


## Electrical Characteristics Curves

Fig. $5 \mathrm{~V}_{\mathrm{BE}(\text { sat })}$ vs. Collector Current


Fig. $6 \mathrm{~V}_{\mathrm{CE}(\text { sat })}$ vs. Collector Current


Fig 7. Output Capacitance


## TO-92 Package Outline (Dimensions in millimeters)



TO-92 Ammo-Pack Outline (Dimensions in millimeters)


